

PNP SILICON POWER TRANSISTORS

.... designed for use in general purpose Power amplifier, vertical output application

FEATURES:

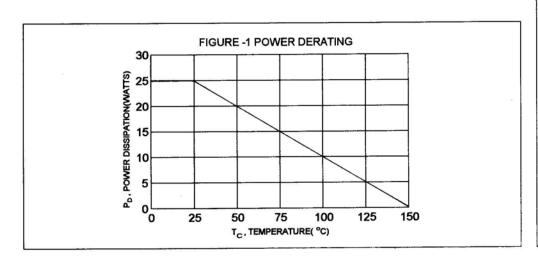
- * Collector-Emitter Voltage V_{ceo}= 150V(Min)
 * DC Current Gain
- - hFE= 40-200@l_c= 400mA
- * Complementary to PNP 2SB546A

MAXIMUM RATINGS

Characteristic	Symbol	2SD401A	Unit
Collector-Emitter Voltage	V _{CEO}	150	V
Collector-Base Voltage	V _{CBO}	200	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current - Continuous - Peak	I _C	2.0 3.0	A
Total Power Dissipation @T _C = 25°C Derate above 25°C	P _D	25 0.2	w/°c
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150	°C

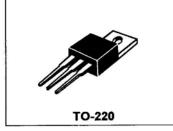
THERMAL CHARACTERISTICS

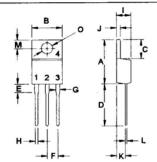
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rθjc	5.0	°C/W



NPN 2SD401A

2 AMPERE **POWER TRANASISTORS** 150 VOLTS 25 WATTS





PIN 1.BASE 2.COLLECTOR 3.EMITTER 4.COLLECTOR(CASE)

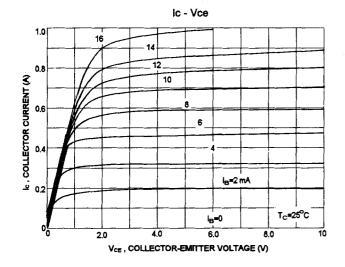
DIM	MILLIMETERS		
DIM	MIN	MAX	
Α	14.68	16.00	
В	9.78	10.42	
C	5.02	6.60	
D	13.00	14.62	
E	3.10	4.19	
F	2.41	2.67	
G	1.10	1.67	
Н	0.69	1.01	
I	3.21	4.98	
J	1.14	1.40	
K	2.20	3.30	
L	0.28	0.61	
M	2.48	3.00	
0	3.50	4.00	

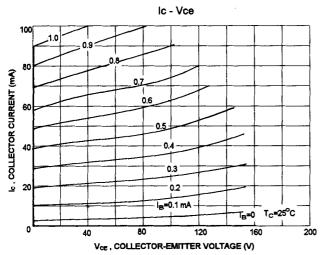
ELECTRICAL CHARACTERISTICS	($T_c = 25^{\circ}C$ unless otherwise noted)
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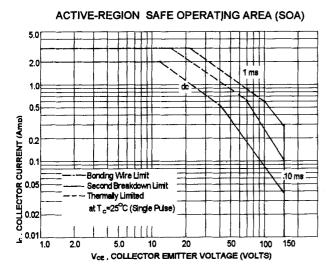
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector Cutoff Current (V _{CB} = 150 V, I _E = 0)	I _{CBO}		50	uA
Emitter Cutoff Current (V _{EB} = 4.0 V, I _C = 0)	I _{EBO}	I _{EBO}		uA
ON CHARACTERISTICS (1)				
DC Current Gain * (I _C = 0.4 A, V _{CE} = 10 V)	hFE(2)	40	200	
Collector-Emitter Saturation Voltage (I _C = 0.5 A, I _B = 50 mA)	V _{CE(sat)}		1.0	٧
DYNAMIC CHARACTERISTICS		1		<u>"</u>
Current-Gain-Bandwidth Product (I _C = 0.4 A, V _{CE} = 10 V, f = 1.0 MHz)	f _T	5.0(typ)		MHz
		I		1

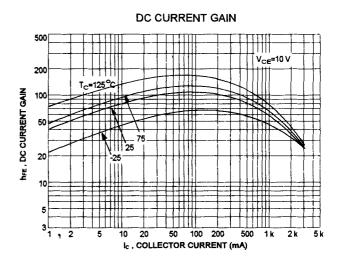
⁽¹⁾ Pulse Test: Pulse Width =300 us,Duty Cycle ≦ 2.0% * hFE(2) Classification:

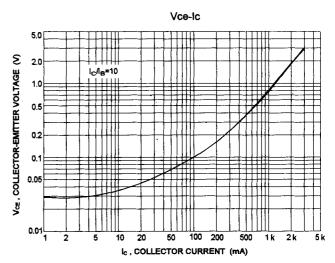
40 M 80 60 L 120 100 K 200











There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $l_{\text{C}}\text{-}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}$ =150 °C; T_c is variable depending on conditions, second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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